

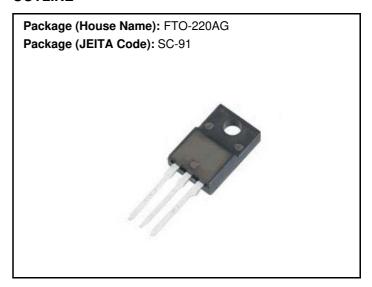
P50F10SN

Power MOSFETs 100V, 50A, N-channel

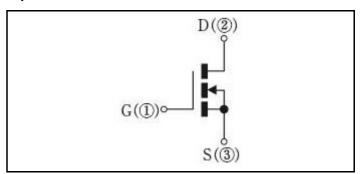
Feature

- N-channel
- Isolated Package
- · Low Ron
- 10V Gate Drive
- · Low Capacitance
- · Pb free terminal
- RoHS:Yes

OUTLINE



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 150	°C
Channel tempertature	Tch		150	°C
Drain-source voltage	V_{DSS}		100	٧
Gate-source voltage	V_{GSS}		±20	٧
Continuous drain current(DC)	I _D		50	А
Continuous drain current(Peak)	I _{DP}	Pulse width 10µs, duty=1/100	200	А
Total power dissipation	P _T		51	W
Single avalanche current	I _{AS}	Starting Tch=25°C Tch≦150°C	43	А
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch≦150°C	92	mJ
Dielectric strenght	Vdis	Terminals to case, AC1min	2	kV
Mounting torque	TOR	(Recommended torque : 0.3N⋅m)	0.5	N∙m

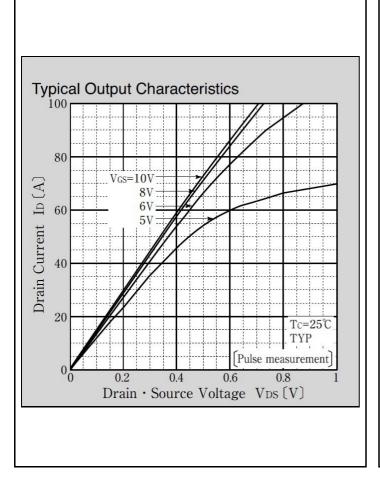
^{* :} See the original Specifications

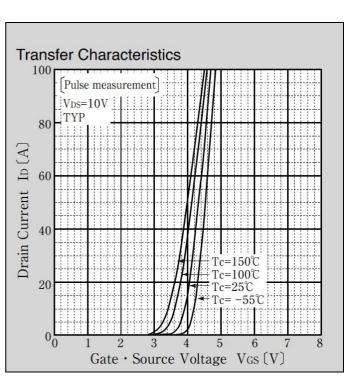
Electrical Characteristics (unless otherwise specified : Tc=25°C)

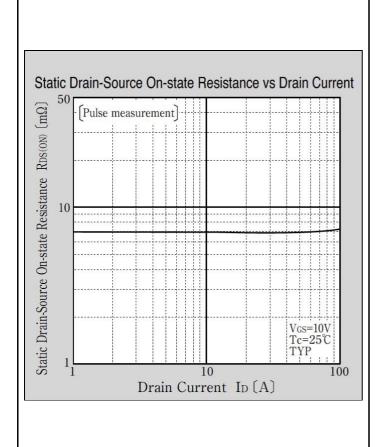
Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	Unit
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	100			٧
Zero gate voltage drain current	I _{DSS}	VDS=100V, VGS=0V			1	μA
Gate-source leakage current	I _{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g _{fs}	ID=25A, VDS=10V	17			S
Static drain-source on-state resistance	R _{DS(ON)}	ID=25A, VGS=10V		0.0069	0.0087	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	V_{SD}	IS=50A, VGS=0V			1.5	٧
Thermal resistance	Rth(j-c)	Junction to case			2.45	°C/W
Total gate charge	Qg	VDD=80V, VGS=10V, ID=50A		114		nC
Gate to source charge	Qgs	VDD=80V, VGS=10V, ID=50A		29		nC
Gate to drain charge	Qgd	VDD=80V, VGS=10V, ID=50A		39		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		5880		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		250		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		530		pF
Turn-on delay time	td(on)	ID=25A, RL=2 Ω , VDD=50V, Rg=0 Ω , VGS(+)=10V, VGS(-)=0V		12		ns
Rise time	tr	ID=25A, RL=2 Ω , VDD=50V, Rg=0 Ω , VGS(+)=10V, VGS(-)=0V		28		ns
Turn-off delay time	td(off)	ID=25A, RL=2 Ω , VDD=50V, Rg=0 Ω , VGS(+)=10V, VGS(-)=0V		65		ns
Fall time	tf	ID=25A, RL=2 Ω , VDD=50V, Rg=0 Ω , VGS(+)=10V, VGS(-)=0V		49		ns
Diode reverse recovery time	trr	IF=50A, VGS=0V, di/dt=100A/μs		61		ns
Diode reverse recovery charge	Qrr	IF=50A, VGS=0V, di/dt=100A/μs		143		nC

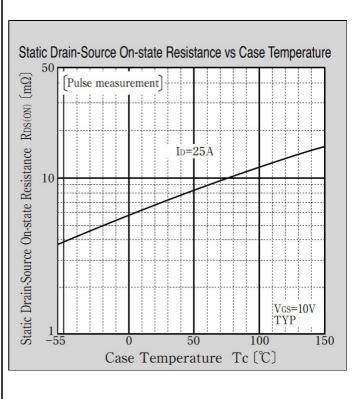
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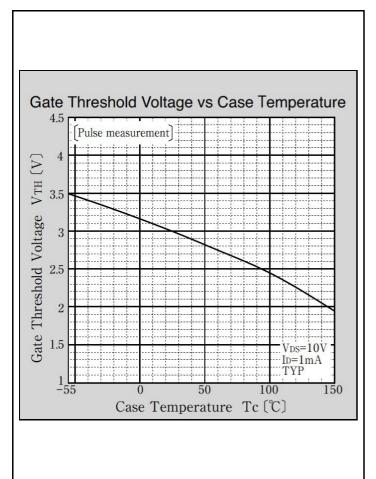
CHARACTERISTIC DIAGRAMS

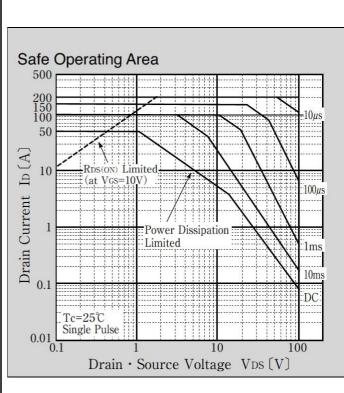


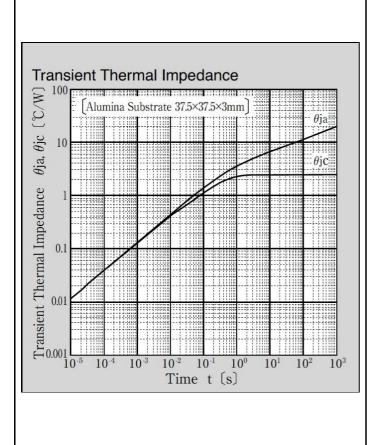


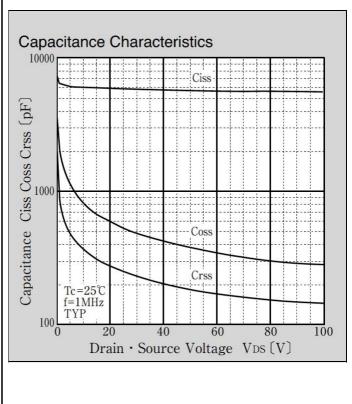


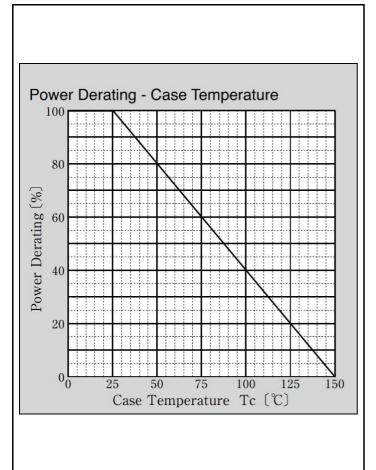


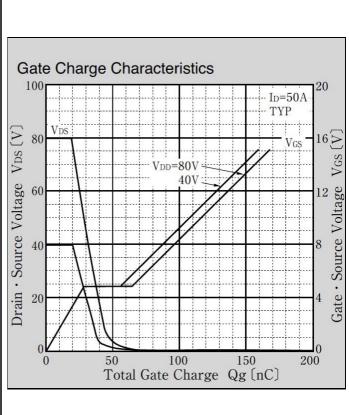


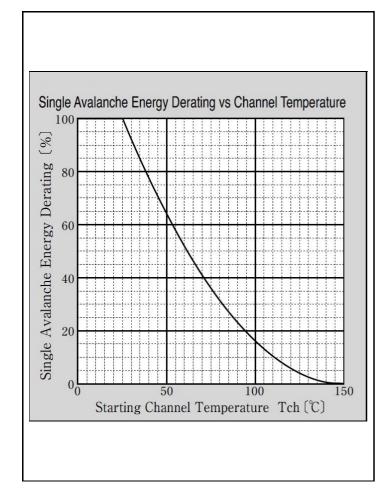








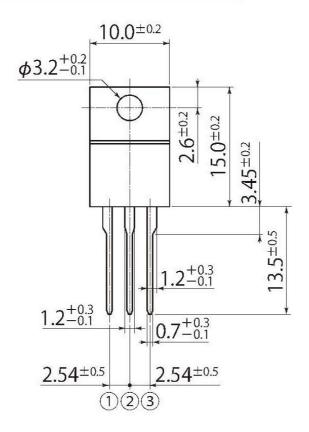


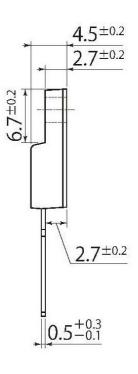


unit:mm

J8

JEDEC Code	_		
JEITA Code	SC-91		
House Name	FTO-220AG(3pin)		





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